

KA1L0380B/KA1L0380RB/KA1M0380RB/ KA1H0380RB

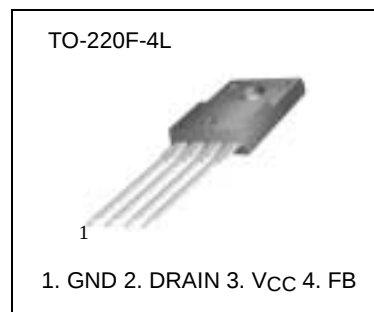
Fairchild Power Switch(SPS)

Features

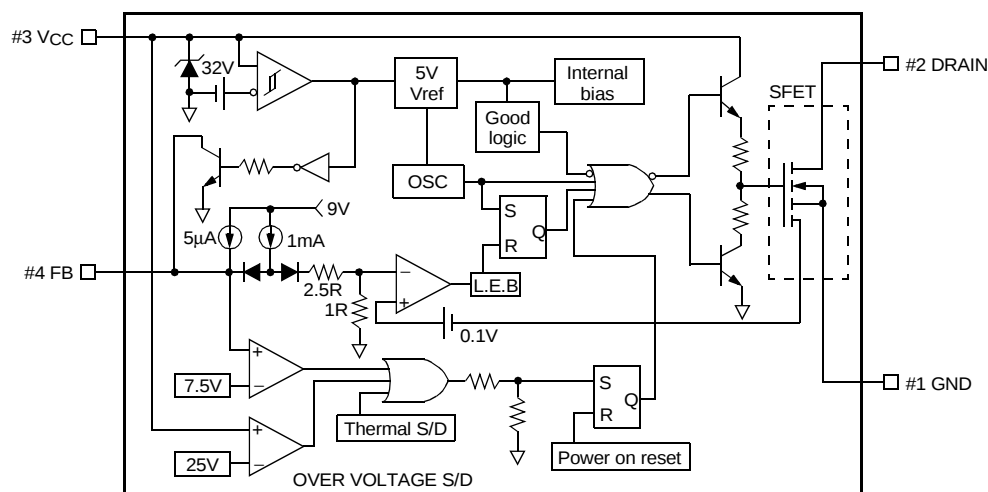
- Precision fixed operating frequency
- KA1L0380B/KA1L0380RB (50KHz)
- KA1M0380RB (67KHz)
- KA1H0380RB (100KHz)
- Pulse by pulse over current limiting
- Over load protection
- Over voltage protection (Min. 23V)
- Internal thermal shutdown function
- Under voltage lockout
- Internal high voltage sense FET
- Auto restart (KA1L0380RB/KA1M0380RB/KA1H0380RB)

Description

The SPS product family is specially designed for an off-line SMPS with minimal external components. The SPS consist of high voltage power SenseFET and current mode PWM controller IC. PWM controller features integrated fixed oscillator, under voltage lock out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, temperature compensated precision current sources for loop compensation and fault protection circuit. Compared to discrete MOSFET and controller or RCC switching converter solution, a SPS can reduce total component count, design size, weight and at the same time increase & efficiency, productivity, and system reliability. It has a basic platform well suited for cost effective design in either a flyback converter or a forward converter.



Internal Block Diagram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-source (GND) voltage ⁽¹⁾	V _{DSS}	800	V
Drain-Gate voltage (R _{GS} =1MΩ)	V _{DGR}	800	V
Gate-source (GND) voltage	V _{GS}	±30	V
Drain current pulsed ⁽²⁾	I _{DM}	12	ADC
Single pulsed avalanche energy ⁽³⁾	E _{AS}	95	mJ
Avalanche current ⁽⁴⁾	I _{AS}	6	A
Continuous drain current (T _C =25°C)	I _D	3.0	ADC
Continuous drain current (T _C =100°C)	I _D	2.1	ADC
Supply voltage	V _{CC}	30	V
Analog input voltage range	V _{FB}	−0.3 to V _{SD}	V
Total power dissipation	P _D	35	W
	Derating	0.28	W/°C
Operating temperature	T _{OPR}	−25 to +85	°C
Storage temperature	T _{STG}	−55 to +150	°C

Notes:

1. T_j=25°C to 150°C
2. Repetitive rating: Pulse width limited by maximum junction temperature
3. L=51mH, V_{DD}=50V, R_G=25Ω, starting T_j=25°C
4. L=13μH, starting T_j=25°C

Electrical Characteristics (SFET part)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Drain-source breakdown voltage	BV _{DSS}	V _{GS} =0V, I _D =50μA	800	-	-	V
Zero gate voltage drain current	I _{DSS}	V _{DS} =Max., Rating, V _{GS} =0V	-	-	50	μA
		V _{DS} =0.8Max., Rating, V _{GS} =0V, T _C =125°C	-	-	200	μA
Static drain-source on resistance ^(Note)	R _{DS(ON)}	V _{GS} =10V, I _D =1.5A	-	4.0	5.0	Ω
Forward transconductance ^(Note)	g _{fs}	V _{DS} =15V, I _D =1.5A	1.5	2.5	-	S
Input capacitance	C _{iss}	V _{GS} =0V, V _{DS} =25V, f=1MHz	-	779	-	pF
Output capacitance	C _{oss}		-	75.6	-	
Reverse transfer capacitance	C _{rss}		-	24.9	-	
Turn on delay time	td(on)	V _{DD} =0.5BV _{DSS} , I _D =3.0A (MOSFET switching time are essentially independent of operating temperature)	-	40	-	nS
Rise time	tr		-	95	-	
Turn off delay time	td(off)		-	150	-	
Fall time	tf		-	60	-	
Total gate charge (gate-source+gate-drain)	Q _g	V _{GS} =10V, I _D =3.0A, V _{DS} =0.5BV _{DSS} (MOSFET switching time are essentially independent of operating temperature)	-	-	34	nC
Gate-source charge	Q _{gs}		-	7.2	-	
Gate-drain (Miller) charge	Q _{gd}		-	12.1	-	

Note:

Pulse test: Pulse width ≤ 300μs, duty cycle ≤ 2%

$$S = \frac{1}{R}$$

Electrical Characteristics (CONTROL part)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
REFERENCE SECTION						
Output voltage ⁽¹⁾	Vref	Ta=25°C	4.80	5.00	5.20	V
Temperature Stability ⁽¹⁾⁽²⁾	Vref/ΔT	−25°C≤Ta≤+85°C	-	0.3	0.6	mV/°C
OSCILLATOR SECTION						
Initial accuracy	FOSC	KA1L0380B	45	50	55	kHz
		KA1L0380RB	45	50	55	
		KA1M0380RB	61	67	73	
		KA1H0380RB	90	100	110	
Frequency change with temperature ⁽²⁾	ΔF/ΔT	−25°C≤Ta≤+85°C	-	±5	±10	%
PWM SECTION						
Maximum duty cycle	Dmax	KA1L0380B	74	77	80	%
		KA1L0380RB	74	77	80	
		KA1M0380RB	74	77	80	
		KA1H0380RB	64	67	70	
FEEDBACK SECTION						
Feedback source current	IFB	Ta=25°C, 0V≤Vfb≤3V	0.7	0.9	1.1	mA
Shutdown delay current	Idelay	Ta=25°C, 5V≤Vfb≤VSD	4.0	5.0	6.0	μA
OVER CURRENT PROTECTION SECTION						
Over current protection	IL(max)	Max. inductor current	1.89	2.15	2.41	A
UVLO SECTION						
Start threshold voltage	Vth(H)	-	14	15	16	V
Minimum operating voltage	Vth(L)	After turn on	9	10	11	V
TOTAL STANDBY CURRENT SECTION						
Start current	IST	VCC=14V	0.1	0.3	0.45	mA
Operating supply current (control part only)	IOPR	Ta=25°C	6	12	18	mA
VCC zener voltage	VZ	ICC=20mA	30	32.5	35	V
SHUTDOWN SECTION						
Shutdown Feedback voltage	VSD	-	6.9	7.5	8.1	V
Thermal shutdown temperature (Tj) ⁽¹⁾	TSD	-	140	160	-	°C
Over voltage protection voltage	VOVP	-	23	25	28	V

Notes:

1. These parameters, although guaranteed, are not 100% tested in production
2. These parameters, although guaranteed, are tested in EDS (wafer test) process

Typical Performance Characteristics

(These characteristic graphs are normalized at $T_a=25^{\circ}\text{C}$)

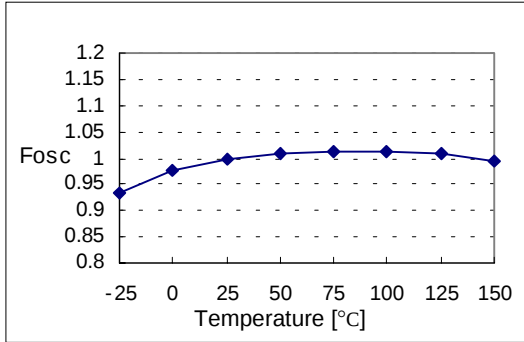


Figure 1. Operating Frequency

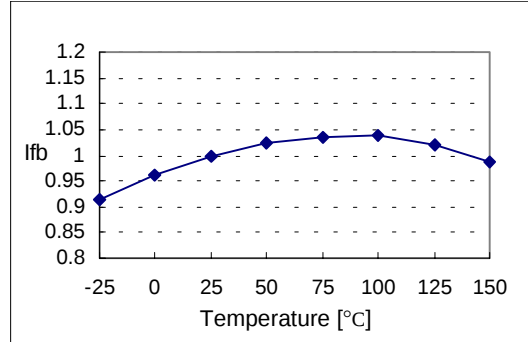


Figure 2. Feedback Source Current

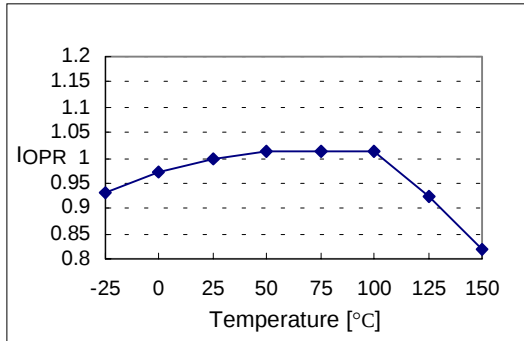


Figure 3. Operating Current

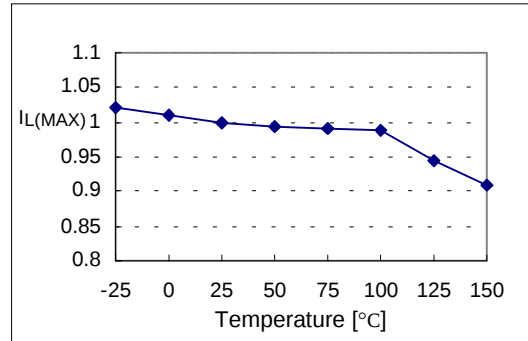


Figure 4. Max. Inductor Current

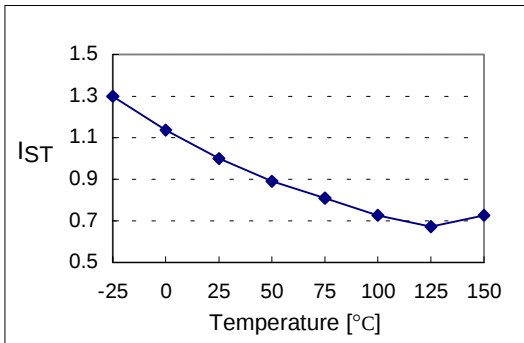


Figure 5. Start up Current

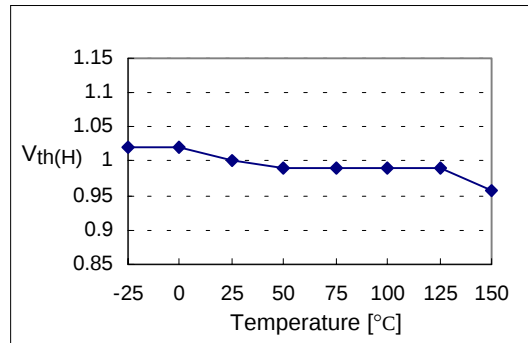


Figure 6. Start Threshold Voltage

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta=25°C)

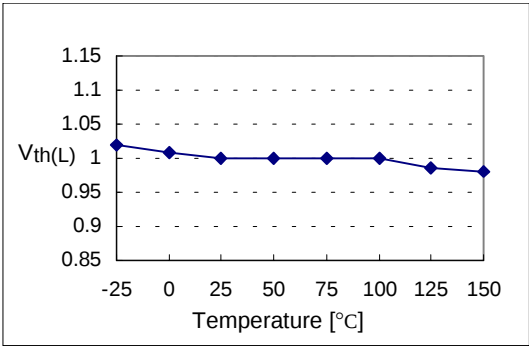


Figure 7. Stop Threshold Voltage

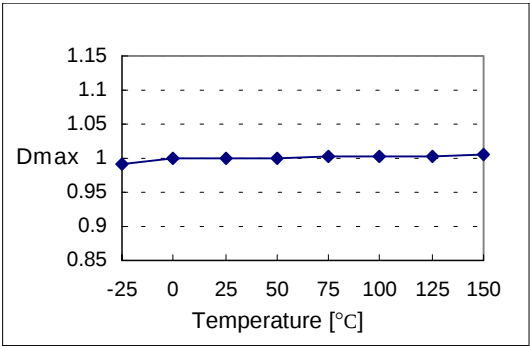


Figure 8. Maximum Duty Cycle

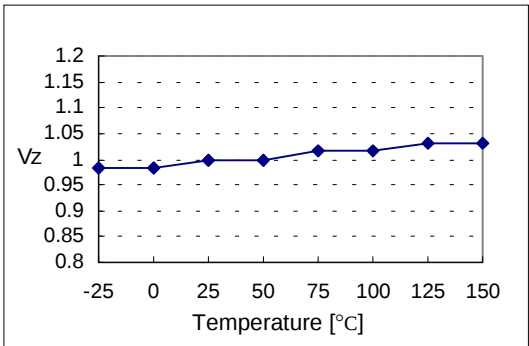


Figure 9. VCC Zener Voltage

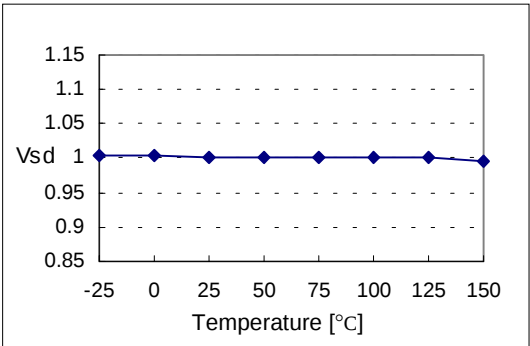


Figure 10. Shutdown Feedback Voltage

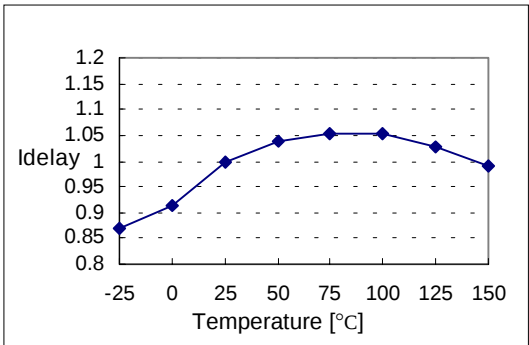


Figure 11. Shutdown Delay Current

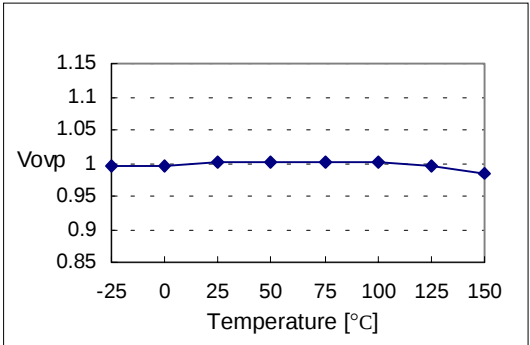


Figure 12. Over Voltage Protection

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at $T_a=25^{\circ}\text{C}$)

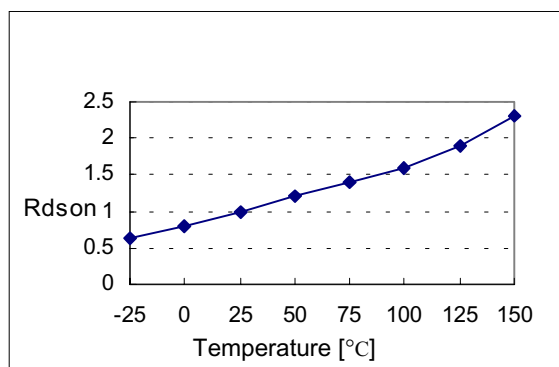
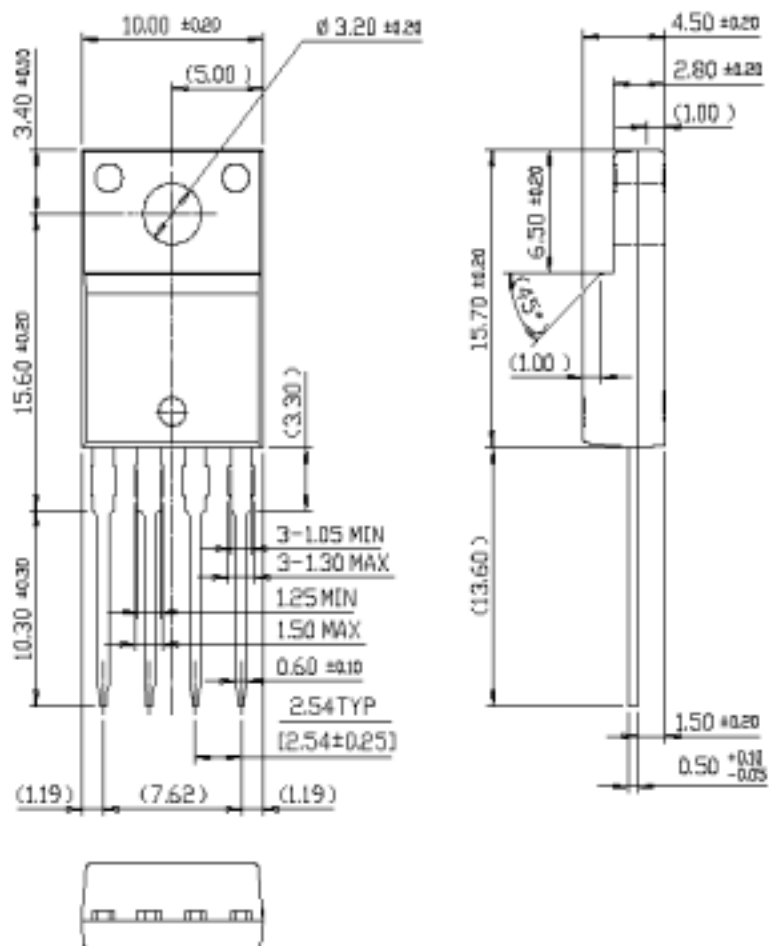


Figure 13. Drain Source Turn-on Resistance

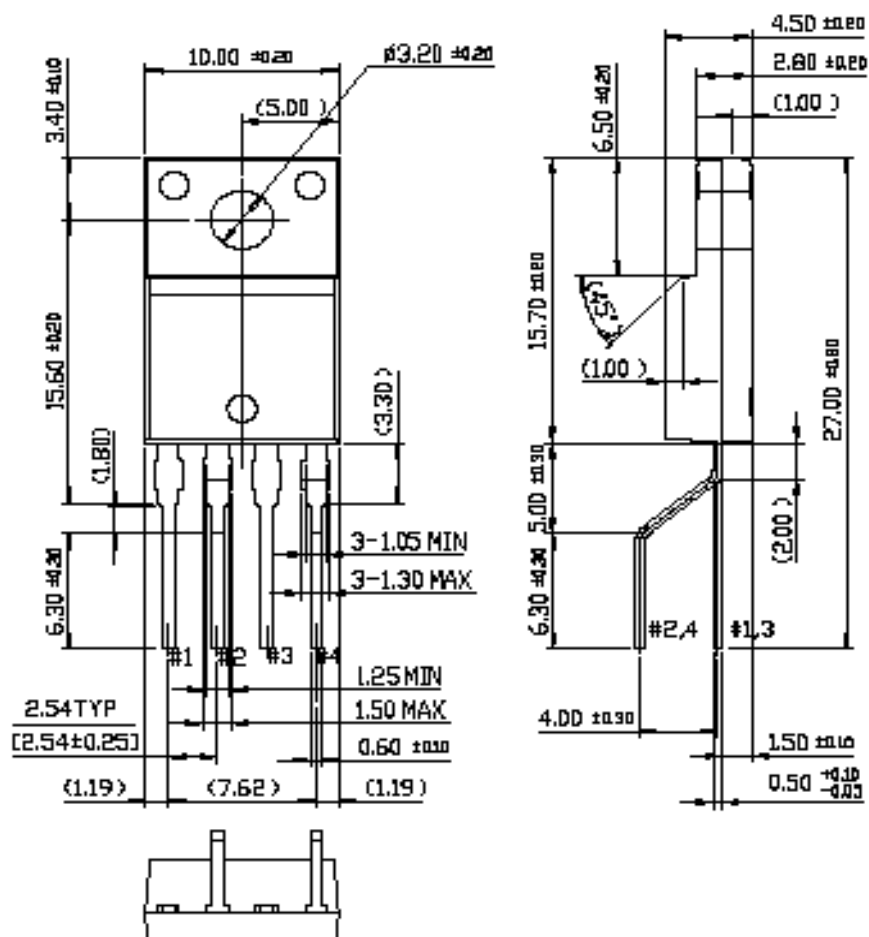
Package Dimensions

TO-220F-4L



Package Dimensions (Continued)

TO-220F-4L (Forming)



Ordering Information

Product Number	Package	Rating	Fosc
KA1L0380B-TU	TO-220F-4L	800V, 3A	50kHz
KA1L0380B-YDTU	TO-220F-4L(Forming)		
KA1L0380RB-TU	TO-220F-4L	800V, 3A	50kHz
KA1L0380RB-YDTU	TO-220F-4L(Forming)		
KA1M0380RB-TU	TO-220F-4L	800V, 3A	67kHz
KA1M0380RB-YDTU	TO-220F-4L(Forming)		
KA1H0380RB-TU	TO-220F-4L	800V, 3A	100kHz
KA1H0380RB-YDTU	TO-220F-4L(Forming)		

TU : Non Forming Type

YDTU : Forming Type

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
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Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.